TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOSIV)

## **TPCC8008**

# Notebook PC Applications Portable Equipment Applications

- Small footprint due to a small and thin package
- Low drain-source ON-resistance:

 $R_{DS (ON)} = 4.5 \text{ m}\Omega \text{ (typ.) ( }V_{GS} = 10 \text{ V)}$ 

- Low leakage current: I<sub>DSS</sub> = 10 μA (max) (V<sub>DS</sub> = 30 V)
- Enhancement mode:  $V_{th}$  = 1.3 to 2.5 V ( $V_{DS}$  = 10 V,  $I_D$  = 1.0 mA)

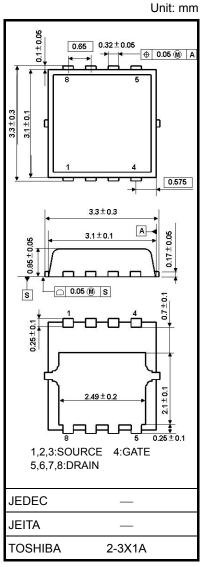
#### Absolute Maximum Ratings (Ta = 25°C)

Characte	eristic	Symbol	Rating	Unit
Drain-source voltage		$V_{DSS}$	30	V
Drain-gate voltage (F	$R_{GS} = 20 \text{ k}\Omega$	$V_{DGR}$	30	V
Gate-source voltage		$V_{GSS}$	±25	٧
Drain current	DC (Note 1)	ΙD	25	Α
Drain current	Pulsed (Note 1)	$I_{DP}$	75	Α
Drain power dissipati	on (Tc = 25°C)	$P_{D}$	30	W
Drain power dissipati	on (t = 10 s) (Note 2a)	$P_{D}$	1.9	W
Drain power dissipation (t = 10 s) (Note 2b)		P <sub>D</sub>	0.7	W
Single-pulse avalanc	he energy (Note 3)	E <sub>AS</sub>	163	mJ
Avalanche current		I <sub>AR</sub>	25	Α
Repetitive avalanche	energy c = 25°C) (Note 4)	E <sub>AR</sub>	2.58	mJ
Channel temperature		T <sub>ch</sub>	150	°C
Storage temperature	range	T <sub>stg</sub>	-55 to 150	°C

Note: For Notes 1 to 4, refer to the next page.

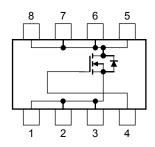
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.02 g (typ.)

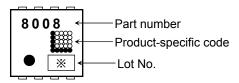
#### **Circuit Configuration**



#### **Thermal Characteristics**

Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case (Tc = 25°C)	R <sub>th (ch-c)</sub>	4.2	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R <sub>th (ch-a)</sub>	66	°C/W
Thermal resistance, channel to ambient $(t = 10 \text{ s})$ (Note 2b)	R <sub>th (ch-a)</sub>	180	°C/W

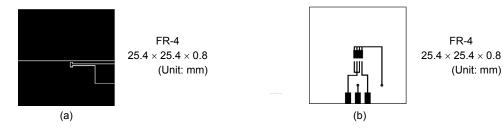
#### Marking (Note 5)



Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a)

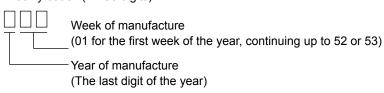
(b) Device mounted on a glass-epoxy board (b)



Note 3:  $V_{DD}$  = 24 V,  $T_{ch}$  = 25°C (initial), L = 200  $\mu$ H,  $R_G$  = 25  $\Omega$ ,  $I_{AR}$  = 25 A

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: \* Weekly code: (Three digits)

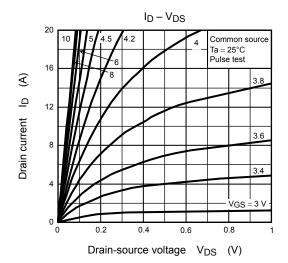


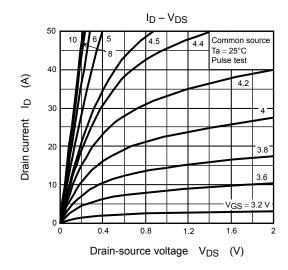
## **Electrical Characteristics (Ta = 25°C)**

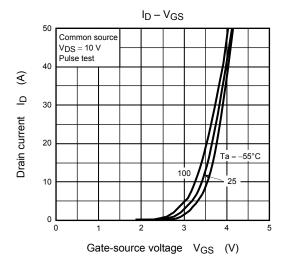
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cui	rent	I <sub>GSS</sub>	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±100	nA
Drain cutoff curre	ent	I <sub>DSS</sub>	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V	_	_	10	μА
Drain-source bre	akdown voltago	V <sub>(BR) DSS</sub>	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	30	_	_	V
Dialii-source bre	akdowii vollage	V <sub>(BR) DSX</sub>	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	±100 10	V		
Gate threshold ve	oltage	V <sub>th</sub>	$V_{DS} = 10 \text{ V}, I_D = 1.0 \text{ mA}$	—     8.5     13       —     4.5     6.8		V	
Drain-source ON			$V_{GS} = 4.5 \text{ V}, I_D = 12.5 \text{ A}$		8.5	13	- mΩ
Drain-source ON-resistance Forward transfer admittance		R <sub>DS</sub> (ON)	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 12.5 A		4.5	6.8	
Forward transfer	admittance	Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 12.5 A	22	43		S
Input capacitance		C <sub>iss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	1600	_	pF
Reverse transfer capacitance		C <sub>rss</sub>		_	290	_	
Reverse transfer capacitance  Output capacitance		Coss		_	470	_	
· · ·	Rise time	t <sub>r</sub>	10 V □ In = 12 5 A		7.9		
Switching time	Turn-on time	t <sub>on</sub>	$V_{GS}$ 10 $V$ $I_D = 12.5 A$ $V_{OUT}$	_	15	_	ns
Switching time	Fall time	t <sub>f</sub>	$\begin{array}{c c} C & & & \\ C & & & \\ C & & & \\ \end{array}$ $\begin{array}{c c} V_{DD} \approx 15 \text{ V} \\ \end{array}$ $\begin{array}{c c} Duty \leq 1\%, \ t_W = 10 \ \mu s \end{array}$	_	16	_	115
	Turn-off time	t <sub>off</sub>		_	42	_	
Total gate charge (gate-source plus		Qg		_	30	_	_
Gate-source charge 1		Q <sub>gs1</sub>	$V_{DD} \approx 24 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 25 \text{ A}$		5.9		nC
Gate-drain ("Mille	er") charge	Q <sub>gd</sub>	and instituted and	_	9.6	_	

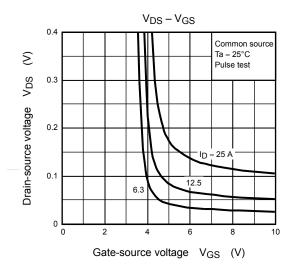
### **Source-Drain Ratings and Characteristics (Ta = 25°C)**

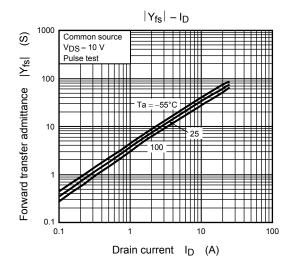
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit	
Drain reverse current	Pulse	(Note 1)	I <sub>DRP</sub>	_	_	_	75	Α
Forward voltage (diode)			$V_{DSF}$	$I_{DR} = 25 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	-1.2	V

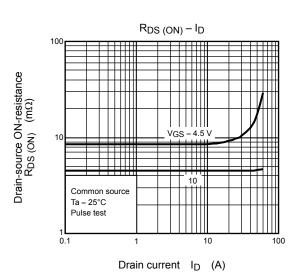


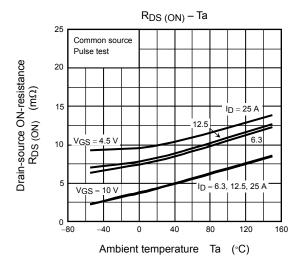


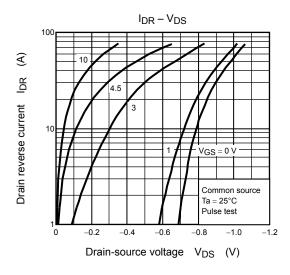


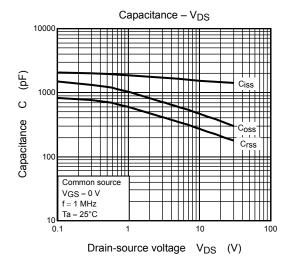


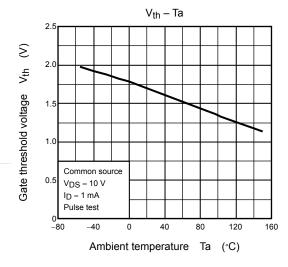


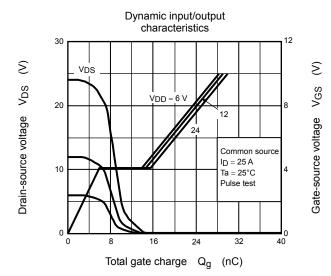




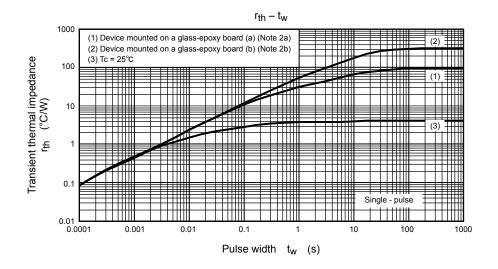


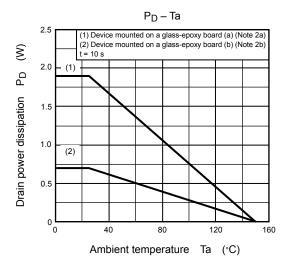


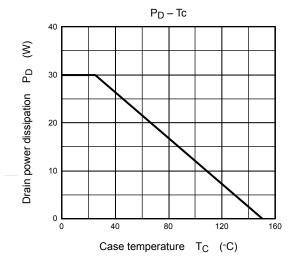


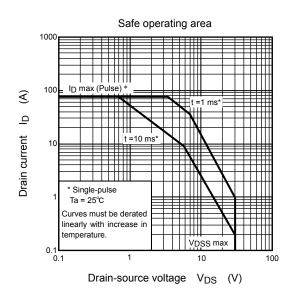


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